1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (†)

| Vcc | 6.5V |
|-----------------------------------|--------------------|
| All inputs and outputs w.r.t. Vss | -0.6V to Vcc +1.0V |
| Storage temperature | 65°C to 150°C |
| Ambient temperature under bias | -40°C to 125°C |
| ESD protection on all pins | |

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

| | DC CHARACTERISTICS | | | : TA = -4 (E): TA = -4 | 0°C to +8 | |
|---------------|--------------------|---|---------|---------------------------|-----------|--|
| Param. No. | Sym. | Characteristic | Min. | Max. | Units | Test Conditions |
| D001 | VIH1 | High-level input voltage | 0.7 Vcc | Vcc+1 | V | _ |
| D002 | VIL1 | Low-level input | -0.3 | 0.3 Vcc | V | $VCC \ge 2.7V$ |
| D003 | VIL2 | voltage | -0.3 | 0.2 Vcc | V | Vcc < 2.7V |
| D004 | VOL1 | Low-level output | _ | 0.4 | V | IOL = 2.1 mA |
| D005 | VOL2 | voltage | _ | 0.2 | V | IOL = 1.0 mA, VCC < 2.5V |
| D006 | Voн | High-level output voltage | Vcc-0.5 | — | V | Іон = -400 μА |
| D007 | ILI | Input leakage current | | ±1 | μΑ | CS = Vcc, VIN = Vss or Vcc |
| D008 | ILO | Output leakage current | | ±1 | μΑ | CS = Vcc, Vout = Vss or Vcc |
| D009 | CINT | Internal Capacitance (all inputs and outputs) | _ | 7 | pF | Ta = 25°C, CLK = 1.0 MHz, Vcc = 5.0V (Note) |
| D010 | ICC Read | | _ | 5 | mA | Vcc = 5.5V; Fclk = 10.0 MHz; |
| | | Operating Current | _ | 2.5 | mA | SO = Open Vcc = 2.5V; FcLк = 5.0 MHz; SO = Open |
| D011 | Icc Write | | _ | 5 | mA | Vcc = 5.5V |
| | | | | 3 | mA | Vcc = 2.5V |
| D012 | lccs | Standby Current | — | 5 | μΑ | \overline{CS} = Vcc = 5.5V, Inputs tied to Vcc or Vss, TA = +125°C |
| | | | | 1 | μA | \overline{CS} = Vcc = 5.5V, Inputs tied to Vcc or Vss, TA = +85°C |

Note: This parameter is periodically sampled and not 100% tested.

| AC CHARACTERISTICS | | Industrial (I): TA = -40° C to + Automotive (E): TA = -40° C to + | | | | |
|--------------------|------|--|-------------------|------------------|-------------------|--|
| Param. No. | Sym. | Characteristic | Min. | Max. | Units | Test Conditions |
| 1 | FCLK | Clock Frequency | | 10 5 3 | MHz MHz MHz | $4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$ |
| 2 | Tcss | CS Setup Time | 50 100 150 | | ns ns ns | $4.5V \le VCC \le 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$ |
| 3 | Тсѕн | CS Hold Time | 100 200 250 | | ns ns ns | $4.5V \le Vcc \le 5.5V$ $2.5V \le Vcc < 4.5V$ $1.8V \le Vcc < 2.5V$ |
| 4 | TCSD | CS Disable Time | 50 | — | ns | — |
| 5 | Tsu | Data Setup Time | 10 20 30 | | ns ns ns | $4.5V \le VCC \le 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$ |
| 6 | Тно | Data Hold Time | 20 40 50 | | ns ns ns | $4.5V \le VCC \le 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$ |
| 7 | TR | CLK Rise Time | — | 2 | μs | (Note 1) |
| 8 | TF | CLK Fall Time | _ | 2 | μs | (Note 1) |
| 9 | Тні | Clock High Time | 50 100 150 | | ns ns ns | $4.5V \le VCC \le 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$ |
| 10 | Tlo | Clock Low Time | 50 100 150 | | ns ns ns | $4.5V \le VCC \le 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$ |
| 11 | TCLD | Clock Delay Time | 50 | _ | ns | — |
| 12 | TCLE | Clock Enable Time | 50 | | ns | — |
| 13 | Τv | Output Valid from Clock Low | | 50 100 160 | ns ns ns | $4.5V \le VCC \le 5.5V$ $2.5V \le VCC < 4.5V$ $1.8V \le VCC < 2.5V$ |
| 14 | Тно | Output Hold Time | 0 | | ns | (Note 1) |
| 15 | TDIS | Output Disable Time | | 40 80 160 | ns ns ns | 4.5V ≤ VCC ≤ 5.5V (Note 1) 2.5V ≤ VCC < 4.5V (Note 1) 1.8V ≤ VCC < 2.5V (Note 1) |
| 16 | Тнs | HOLD Setup Time | 20 40 80 | | ns ns ns | $\begin{array}{l} 4.5V \leq VCC \leq 5.5V \\ 2.5V \leq VCC < 4.5V \\ 1.8V \leq VCC < 2.5V \end{array}$ |

TABLE 1-2:AC CHARACTERISTICS

Note 1: This parameter is periodically sampled and not 100% tested.

2: Twc begins on the rising edge of $\overline{\text{CS}}$ after a valid write sequence and ends when the internal write cycle is complete.

3: This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model which can be obtained from our web site: www.microchip.com.

| TABLE 1-2 : | AC CHARACTERISTICS (CONTINUED) |
|--------------------|--------------------------------|
|--------------------|--------------------------------|

| AC CHARACTERISTICS | | | Industrial (I) Automotive | | | |
|--------------------|------|------------------------------|------------------------------|------|----------------|--|
| Param. No. | Sym. | Characteristic | Min. | Max. | Units | Test Conditions |
| 17 | Тнн | HOLD Hold Time | 20 40 80 | | ns ns ns | $\begin{array}{l} 4.5V \leq Vcc \leq 5.5V \\ 2.5V \leq Vcc < 4.5V \\ 1.8V \leq Vcc < 2.5V \end{array}$ |
| 18 | Тнz | HOLD Low to Output High-Z | 30 60 160 | | ns ns ns | 4.5V ≤ VCC ≤ 5.5V (Note 1) 2.5V ≤ VCC < 4.5V (Note 1) 1.8V ≤ VCC < 2.5V (Note 1) |
| 19 | Тн∨ | HOLD High to Output Valid | 30 60 160 | | ns ns ns | $\begin{array}{l} 4.5V \leq Vcc \leq 5.5V \\ 2.5V \leq Vcc < 4.5V \\ 1.8V \leq Vcc < 2.5V \end{array}$ |
| 20 | Twc | Internal Write Cycle Time | _ | 5 | ms | (Note 2) |
| 21 | | Endurance | 1M | | E/W Cycles | 25°C, Vcc = 5.5V (Note 3) |

Note 1: This parameter is periodically sampled and not 100% tested.

2: Twc begins on the rising edge of $\overline{\text{CS}}$ after a valid write sequence and ends when the internal write cycle is complete.

3: This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance[™] Model which can be obtained from our web site: www.microchip.com.

TABLE 1-3:AC TEST CONDITIONS

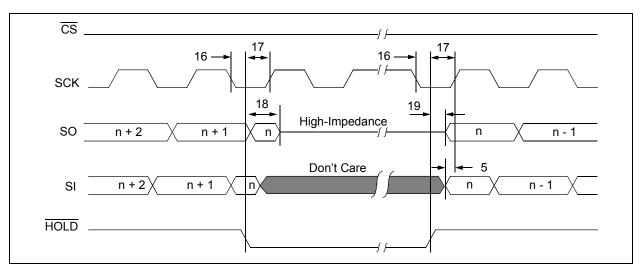
| AC Waveform: | | | | |
|------------------------------------|--|--|--|--|
| — | | | | |
| (Note 1) | | | | |
| (Note 2) | | | | |
| — | | | | |
| Timing Measurement Reference Level | | | | |
| 0.5 Vcc | | | | |
| 0.5 Vcc | | | | |
| | | | | |

Note 1: For VCC $\leq 4.0V$

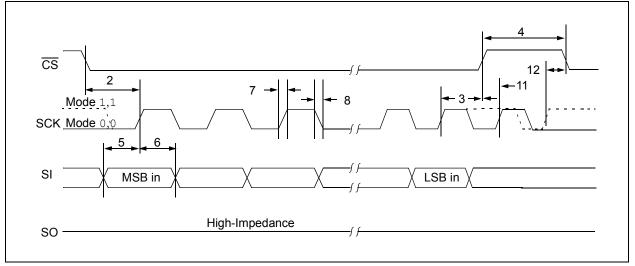
2: For Vcc > 4.0V

25XX080C/D

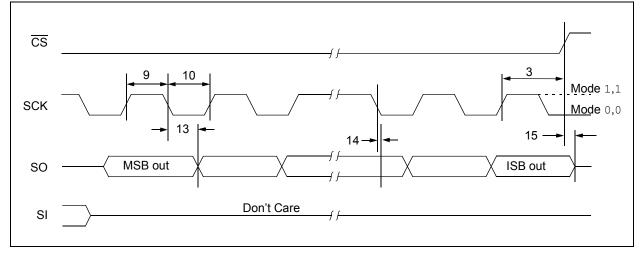
FIGURE 1-1: HOLD TIMING











 $[\]ensuremath{\textcircled{}^\circ}$ 2009-2012 Microchip Technology Inc.

2.0 FUNCTIONAL DESCRIPTION

2.1 Principles of Operation

The 25XX080C/D are 1024 byte Serial EEPROMs designed to interface directly with the Serial Peripheral Interface (SPI) Port of many of today's popular microcontroller families, including Microchip's PIC[®] microcontrollers. It may also interface with microcontrollers that do not have a built-in Synchronous Serial Port by using discrete

I/O lines programmed properly with the software.

The 25XX080C/D contains an 8-bit instruction register. The device is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The \overline{CS} pin must be low and the HOLD pin must be high for the entire operation.

Table 2-1 contains a list of the possible instruction bytes and format for device operation. All instructions, addresses, and data are transferred MSB first, LSB last.

Data <u>(SI)</u> is sampled on the first rising edge of SCK after CS goes low. If the clock line is shared with other peripheral devices on the SPI bus, the user can assert the HOLD input and place the 25XX080C/D in 'HOLD' mode. After releasing the HOLD pin, operation will resume from the point when the HOLD was asserted.

2.2 Read Sequence

The device is selected by pulling \overline{CS} low. The 8-bit READ instruction is transmitted to the 25XX080C/D followed by the 16-bit address, with the six MSBs of the address being "don't care" bits. After the correct READ instruction and address are sent, the data stored in the memory at the selected address is shifted out on the SO pin. The data stored in the memory at the next address can be read sequentially by continuing to provide clock pulses. The internal Address Pointer is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached (03FFh), the address counter rolls over to address 0000h allowing the read cycle to be continued indefinitely. The read operation is terminated by raising the \overline{CS} pin (Figure 2-1).

2.3 Write Sequence

Prior to any attempt to write data to the 25XX080C/D, the write enable latch must be set by issuing the WREN instruction (Figure 2-4). This is done by setting \overline{CS} low and then clocking out the proper instruction into the 25XX080C/D. After all eight bits of the instruction are transmitted, the \overline{CS} must be brought high to set the write enable latch. If the write operation is initiated immediately after the WREN instruction without \overline{CS} being brought high, the data will not be written to the array because the write enable latch will not have been properly set.

Once the write enable latch is set, the user may proceed by setting the \overline{CS} low, issuing a WRITE instruction, followed by the 16-bit address, with the six MSBs of the address being "don't care" bits, and then the data to be written. Up to 16 bytes (25XX080C) or 32 bytes (25XX080D) of data can be sent to the device before a write cycle is necessary. The only restriction is that all of the bytes must reside in the same page.

Note: Page write operations are limited to writing bytes within a single physical page, regardless of the number of bytes actually being written. Physical page boundaries start at addresses that are integer multiples of the page buffer size (or 'page size') and, end at addresses that are integer multiples of page size - 1. If a Page Write command attempts to write across a physical page boundary, the result is that the data wraps around to the beginning of the current page (overwriting data previously stored there), instead of being written to the next page as might be expected. It is therefore necessary for the application software to prevent page write operations that would attempt to cross a page boundary.

For the data to be actually written to the array, the \overline{CS} must be brought high after the Least Significant bit (D0) of the *n*th data byte has been clocked in. If \overline{CS} is brought high at any other time, the write operation will not be completed. Refer to Figure 2-2 and Figure 2-3 for more detailed illustrations on the byte write sequence and the page write sequence, respectively. While the write is in progress, the STATUS register may be read to check the status of the WPEN, WIP, WEL, BP1 and BP0 bits (Figure 2-6). A read attempt of a memory array location will not be possible during a write cycle. When the write cycle is completed, the write enable latch is reset.

25XX080C/D

Block Diagram

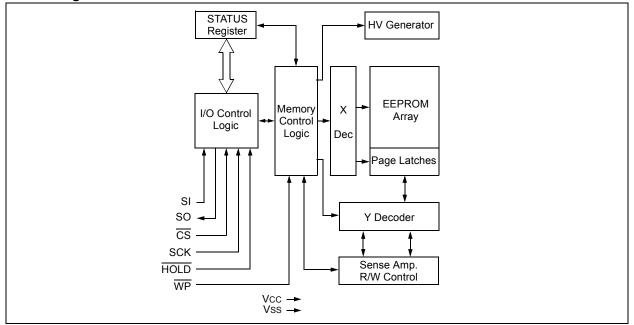
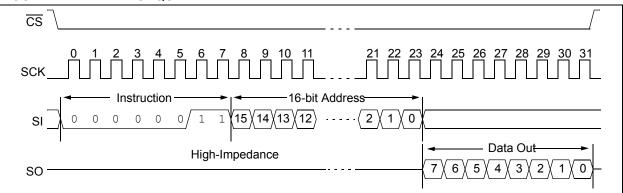


TABLE 2-1: INSTRUCTION SET

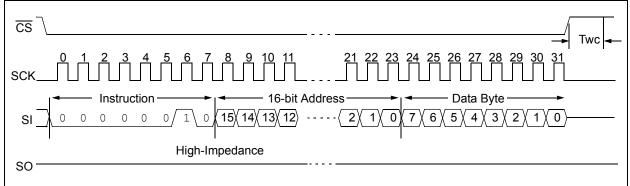
| Instruction Name | Instruction Format | Description |
|------------------|--------------------|---|
| READ | 0000 0011 | Read data from memory array beginning at selected address |
| WRITE | 0000 0010 | Write data to memory array beginning at selected address |
| WRDI | 0000 0100 | Reset the write enable latch (disable write operations) |
| WREN | 0000 0110 | Set the write enable latch (enable write operations) |
| RDSR | 0000 0101 | Read STATUS Register |
| WRSR | 0000 0001 | Write STATUS Register |



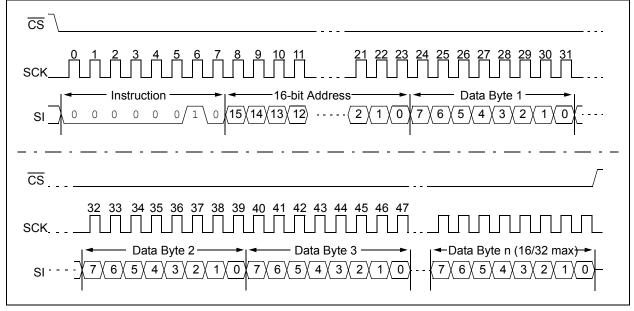


^{© 2009-2012} Microchip Technology Inc.









2.4 Write Enable (WREN) and Write Disable (WRDI)

The 25XX080C/D contains a write enable latch. See Table 2-4 for the Write-Protect Functionality Matrix. This latch must be set before any write operation will be completed internally. The WREN instruction will set the latch, and the WRDI will reset the latch.

The following is a list of conditions under which the write enable latch will be reset:

- Power-up
- + WRDI instruction successfully executed
- WRSR instruction successfully executed
- WRITE instruction successfully executed



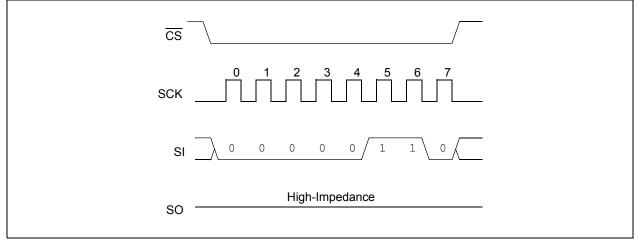
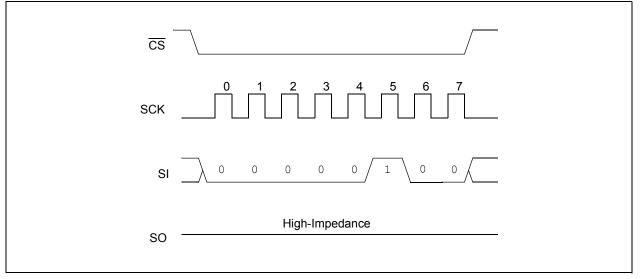


FIGURE 2-5: WRITE DISABLE SEQUENCE (WRDI)



^{© 2009-2012} Microchip Technology Inc.

2.5 Read Status Register (RDSR) Instruction

The Read Status Register (RDSR) instruction provides access to the STATUS register. The STATUS register may be read at any time, even during a write cycle. The STATUS register is formatted as follows:

| TABLE 2-2: | STATUS REGISTER |
|------------|-----------------|
| | |

| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|---------|---|---|---|-----|-----|-----|-----|
| W/R | Ι | - | Ι | W/R | W/R | R | R |
| WPEN | Х | Х | Х | BP1 | BP0 | WEL | WIP |
| W/R = w | W/R = writable/readable. R = read-only. | | | | | | |

The **Write-In-Process (WIP)** bit indicates whether the 25XX080C/D is busy with a write operation. When set to a '1', a write is in progress, when set to a '0', no write is in progress. This bit is read-only.

The **Write Enable Latch (WEL)** bit indicates the status of the write enable latch and is read only. When set to a '1', the latch allows writes to the array or the STATUS register, when set to a '0', the latch prohibits writes to the array or the STATUS register. The state of this bit can always be updated via the WREN or WRDI commands regardless of the state of write protection on the STATUS register. These commands are shown in Figure 2-4 and Figure 2-5.

The **Block Protection (BP0 and BP1)** bits indicate which blocks are currently write-protected. These bits are set by the user issuing the WRSR instruction, which is in Figure 2-7. These bits are nonvolatile and are shown in Table 2-3.

See Figure 2-6 for the RDSR timing sequence.

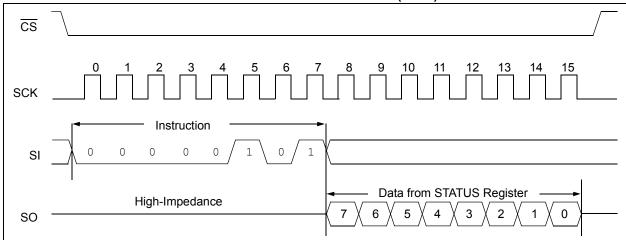


FIGURE 2-6: READ STATUS REGISTER TIMING SEQUENCE (RDSR)

2.6 Write Status Register (WRSR) Instruction

The Write Status Register (WRSR) instruction allows the user to write to the nonvolatile bits in the STATUS register as shown in Table 2-2. The user is able to select one of four levels of protection for the array by writing to the appropriate bits in the STATUS register. The array is divided up into four segments. The user has the ability to write-protect none, one, two or all four of the segments of the array. The partitioning is controlled as shown in Table 2-3.

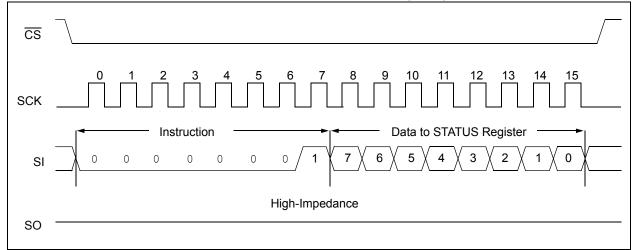
The Write-Protect Enable (WPEN) bit is also a nonvolatile bit that is available as an enable bit for the WP pin. The Write-Protect (WP) pin and the Write-Protect Enable (WPEN) bit in the STATUS register control the programmable hardware write-protect feature. Hardware write protection is enabled when WP pin is low and the WPEN bit is high. Hardware write protection is disabled when either the WP pin is high or the WPEN bit is low. When the chip is hardware write-protected, only writes to nonvolatile bits in the STATUS register are disabled. See Table 2-4 for a matrix of functionality on the WPEN bit.

See Figure 2-7 for the WRSR timing sequence.

TABLE 2-3:ARRAY PROTECTION

| BP1 | BP0 | Array Addresses Write-Protected |
|-----|-----|------------------------------------|
| 0 | 0 | none |
| 0 | 1 | upper 1/4 (0300h-03FFh) |
| 1 | 0 | upper 1/2 (0200h-03FFh) |
| 1 | 1 | all (0000h-03FFh) |

FIGURE 2-7: WRITE STATUS REGISTER TIMING SEQUENCE (WRSR)



^{© 2009-2012} Microchip Technology Inc.

2.7 Data Protection

The following protection has been implemented to prevent inadvertent writes to the array:

- The write enable latch is reset on power-up
- A write enable instruction must be issued to set the write enable latch
- After a byte write, page write or STATUS register write, the write enable latch is reset
- CS must be set high after the proper number of clock cycles to start an internal write cycle
- Access to the array during an internal write cycle is ignored and programming is continued

2.8 Power-On State

The 25XX080C/D powers on in the following state:

- The device is in low-power Standby mode (CS = 1)
- The write enable latch is reset
- SO is in high-impedance state
- A high-to-low-level transition on CS is required to enter active state

TABLE 2-4: WRITE-PROTECT FUNCTIONALITY MATRIX

| WEL (SR bit 1) | WPEN (SR bit 7) | WP (pin 3) | Protected Blocks | Unprotected Blocks | STATUS Register |
|-------------------|--------------------|---------------|------------------|--------------------|-----------------|
| 0 | х | х | Protected | Protected | Protected |
| 1 | 0 | х | Protected | Writable | Writable |
| 1 | 1 | 0 (low) | Protected | Writable | Protected |
| 1 | 1 | 1 (high) | Protected | Writable | Writable |

x = don't care

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

| Name | Pin Number | Function |
|------|------------|--------------------|
| CS | 1 | Chip Select Input |
| SO | 2 | Serial Data Output |
| WP | 3 | Write-Protect Pin |
| Vss | 4 | Ground |
| SI | 5 | Serial Data Input |
| SCK | 6 | Serial Clock Input |
| HOLD | 7 | Hold Input |
| Vcc | 8 | Supply Voltage |

| TABLE 3-1: | PIN FUNCTION TABLE |
|------------|--------------------|
|------------|--------------------|

3.1 Chip Select (CS)

A low level on this pin selects the device. A high level deselects the device and forces it into Standby mode. However, a programming cycle which is already initiated or in progress will be completed, regardless of the \overline{CS} input signal. If \overline{CS} is brought high during a program cycle, the device will go into Standby mode as soon as the programming cycle is complete. When the device is deselected, SO goes to the high-impedance state, allowing multiple parts to share the same SPI bus. A low-to-high transition on \overline{CS} after a valid write sequence initiates an internal write cycle. After power-up, a low level on \overline{CS} is required prior to any sequence being initiated.

3.2 Serial Output (SO)

The SO pin is used to transfer data out of the 25XX080C/D. During a read cycle, data is shifted out on this pin after the falling edge of the serial clock.

3.3 Write-Protect (WP)

This pin is used in conjunction with the WPEN bit in the STATUS register to prohibit writes to the nonvolatile bits in the STATUS register. When WP is low and WPEN is high, writing to the nonvolatile bits in the STATUS register is disabled. All other operations function normally. When WP is high, all functions, including writes to the nonvolatile bits in the STATUS register operate normally. If the WPEN bit is set, WP low during a STATUS register write sequence will disable writing to the STATUS register. If an internal write cycle has already begun, WP going low will have no effect on the write.

The \overline{WP} pin function is blocked when the WPEN bit in the STATUS register is low. This allows the user to install the 25XX080C/D in a system with \overline{WP} pin grounded and still be able to write to the STATUS register. The \overline{WP} pin functions will be enabled when the WPEN bit is set high.

3.4 Serial Input (SI)

The SI pin is used to transfer data into the device. It receives instructions, addresses and data. Data is latched on the rising edge of the serial clock.

3.5 Serial Clock (SCK)

The SCK is used to synchronize the communication between a master and the 25XX080C/D. Instructions, addresses or data present on the SI pin are latched on the rising edge of the clock input, while data on the SO pin is updated after the falling edge of the clock input.

3.6 Hold (HOLD)

The HOLD pin is used to suspend transmission to the 25XX080C/D while in the middle of a serial sequence without having to retransmit the entire sequence again. It must be held high any time this function is not being used. Once the device is selected and a serial sequence is underway, the HOLD pin may be pulled low to pause further serial communication without resetting the serial sequence. The HOLD pin must be brought low while SCK is low, otherwise the HOLD function will not be invoked until the next SCK high-tolow transition. The 25XX080C/D must remain selected during this sequence. The SI, SCK and SO pins are in a high-impedance state during the time the device is paused and transitions on these pins will be ignored. To resume serial communication, HOLD must be brought high while the SCK pin is low, otherwise serial communication will not resume. Lowering the HOLD line at any time will tri-state the SO line.

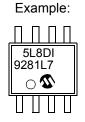
^{© 2009-2012} Microchip Technology Inc.

4.0 PACKAGING INFORMATION

4.1 Package Marking Information

8-Lead MSOP (150 mil)





Example:

<u>п п п п</u>

25LC080D

I/P @3 1L7

10928

Example:

25LC08DI

SN (e3)0928

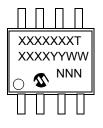
S ^{1L7}

 \cap

8-Lead PDIP





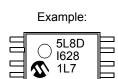


| SOP |
|-----|
| |



8-Lead 2x3 TDFN









| | 1st Line Marking Codes | | | | | | |
|-------------|------------------------|--------|---------|---------|--|--|--|
| Part Number | | | TD | FN | | | |
| | TSSOP | MSOP - | l Temp. | E Temp. | | | |
| 25AA080C | 5A8C | 5A8CT | C31 | — | | | |
| 25AA080D | 5A8D | 5A8DT | C41 | — | | | |
| 25LC080C | 5L8C | 5L8CT | C34 | C35 | | | |
| 25LC080D | 5L8D | 5L8DT | C44 | C45 | | | |

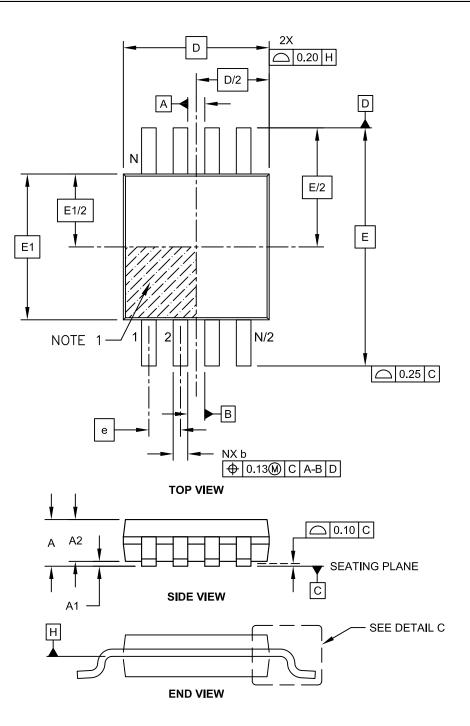
Note: T = Temperature grade (I, E)

| Note: | YY WW NNN ©3 * | Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package. |
|-------|----------------------------|--|
| | be carrie | d over to the next line, thus limiting the number of available s for customer-specific information. |

^{© 2009-2012} Microchip Technology Inc.

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

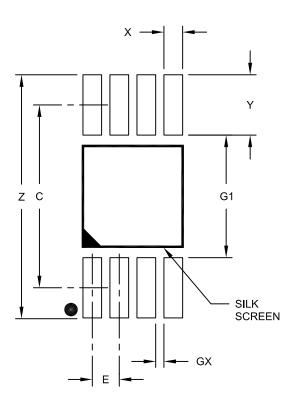
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| | Units | | | S |
|-------------------------|------------------|------|----------|------|
| Dimensior | Dimension Limits | | NOM | MAX |
| Contact Pitch | E | | 0.65 BSC | |
| Contact Pad Spacing | С | | 4.40 | |
| Overall Width | Z | | | 5.85 |
| Contact Pad Width (X8) | X1 | | | 0.45 |
| Contact Pad Length (X8) | Y1 | | | 1.45 |
| Distance Between Pads | G1 | 2.95 | | |
| Distance Between Pads | GX | 0.20 | | |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

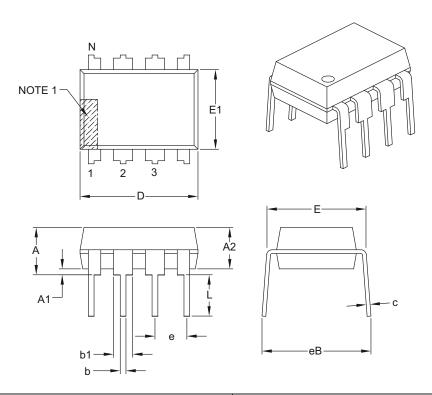
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

^{© 2009-2012} Microchip Technology Inc.

8-Lead Plastic Dual In-Line (P or PA) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | INCHES | |
|----------------------------|----------|------|----------|------|
| Dimensio | n Limits | MIN | NOM | MAX |
| Number of Pins | Ν | | 8 | |
| Pitch | е | | .100 BSC | |
| Top to Seating Plane | Α | — | - | .210 |
| Molded Package Thickness | A2 | .115 | .130 | .195 |
| Base to Seating Plane | A1 | .015 | - | — |
| Shoulder to Shoulder Width | E | .290 | .310 | .325 |
| Molded Package Width | E1 | .240 | .250 | .280 |
| Overall Length | D | .348 | .365 | .400 |
| Tip to Seating Plane | L | .115 | .130 | .150 |
| Lead Thickness | с | .008 | .010 | .015 |
| Upper Lead Width | b1 | .040 | .060 | .070 |
| Lower Lead Width | b | .014 | .018 | .022 |
| Overall Row Spacing § | eB | _ | - | .430 |

Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.

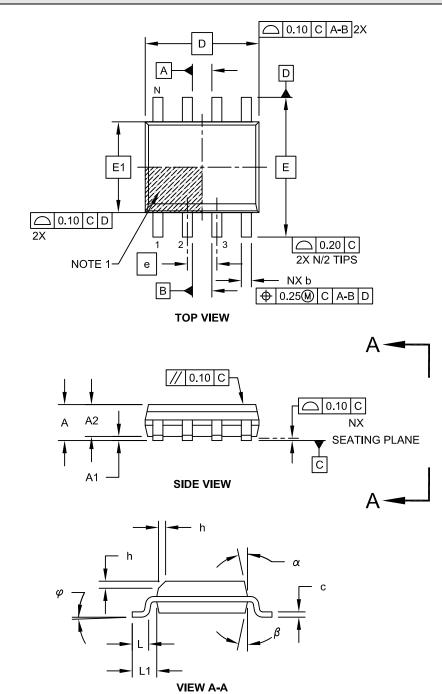
2. § Significant Characteristic.

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.

4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B



8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

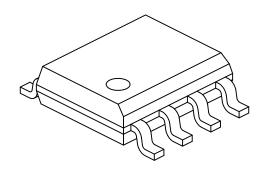
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

Microchip Technology Drawing No. C04-057C Sheet 1 of 2

 $[\]ensuremath{\textcircled{}^\circ}$ 2009-2012 Microchip Technology Inc.

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | N | ILLIMETER | S | |
|--------------------------|------------------|-----------|----------|------|
| Dimension | Dimension Limits | | NOM | MAX |
| Number of Pins | N | | 8 | |
| Pitch | е | | 1.27 BSC | |
| Overall Height | Α | - | - | 1.75 |
| Molded Package Thickness | A2 | 1.25 | - | - |
| Standoff § | A1 | 0.10 | - | 0.25 |
| Overall Width | E | 6.00 BSC | | |
| Molded Package Width | E1 | 3.90 BSC | | |
| Overall Length | D | 4.90 BSC | | |
| Chamfer (Optional) | h | 0.25 | - | 0.50 |
| Foot Length | L | 0.40 | - | 1.27 |
| Footprint | L1 | | 1.04 REF | |
| Foot Angle | φ | 0° | - | 8° |
| Lead Thickness | С | 0.17 | - | 0.25 |
| Lead Width | b | 0.31 | - | 0.51 |
| Mold Draft Angle Top | α | 5° | - | 15° |
| Mold Draft Angle Bottom | β | 5° | - | 15° |

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M

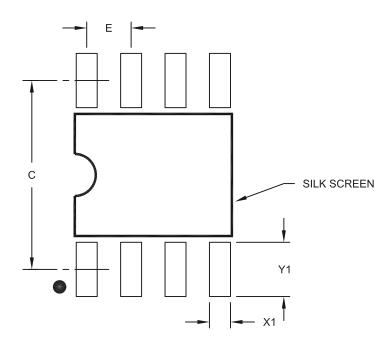
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| | Ν | /ILLIMETER | S | |
|-------------------------|----|-------------------|------|------|
| Dimension Limits | | MIN | NOM | MAX |
| Contact Pitch | E | 1.27 BSC | | |
| Contact Pad Spacing | С | | 5.40 | |
| Contact Pad Width (X8) | X1 | | | 0.60 |
| Contact Pad Length (X8) | Y1 | | | 1.55 |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

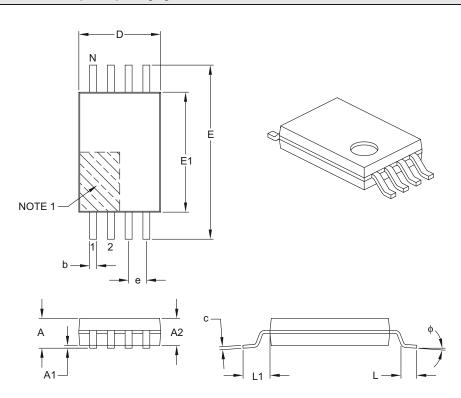
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

^{© 2009-2012} Microchip Technology Inc.

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Units | | MILLIMETERS | | |
|--------------------------|----------|----------|-------------|------|--|
| Dimensior | n Limits | MIN | NOM | MAX | |
| Number of Pins | N | | 8 | | |
| Pitch | е | | 0.65 BSC | | |
| Overall Height | Α | — | — | 1.20 | |
| Molded Package Thickness | A2 | 0.80 | 1.00 | 1.05 | |
| Standoff | A1 | 0.05 | _ | 0.15 | |
| Overall Width | E | 6.40 BSC | | | |
| Molded Package Width | E1 | 4.30 | 4.40 | 4.50 | |
| Molded Package Length | D | 2.90 | 3.00 | 3.10 | |
| Foot Length | L | 0.45 | 0.60 | 0.75 | |
| Footprint | L1 | | 1.00 REF | | |
| Foot Angle | ¢ | 0° | _ | 8° | |
| Lead Thickness | С | 0.09 | _ | 0.20 | |
| Lead Width | b | 0.19 | - | 0.30 | |

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

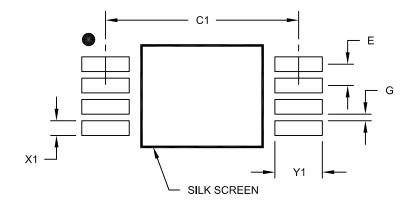
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

| | Units | | | S |
|-------------------------|------------------|----------|------|------|
| Dimension | Dimension Limits | | NOM | MAX |
| Contact Pitch | E | 0.65 BSC | | |
| Contact Pad Spacing | C1 | | 5.90 | |
| Contact Pad Width (X8) | X1 | | | 0.45 |
| Contact Pad Length (X8) | Y1 | | | 1.45 |
| Distance Between Pads | G | 0.20 | | |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

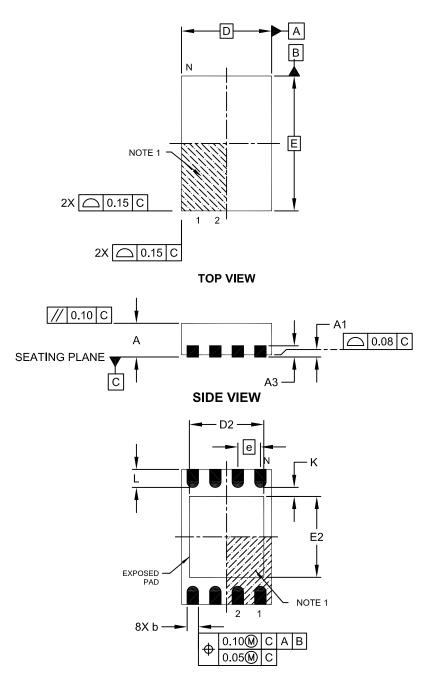
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2086A

^{© 2009-2012} Microchip Technology Inc.

8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75mm Body [TDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

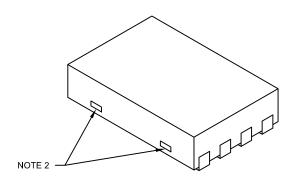


BOTTOM VIEW

Microchip Technology Drawing No. C04-129C Sheet 1 of 2

8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75mm Body [TDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | MILLIMETERS | | | |
|------------------------|-------------|----------|----------|------|
| Dimension | Limits | MIN | NOM | MAX |
| Number of Pins | Ν | | 8 | |
| Pitch | е | | 0.50 BSC | |
| Overall Height | Α | 0.70 | 0.75 | 0.80 |
| Standoff | A1 | 0.00 | 0.02 | 0.05 |
| Contact Thickness | A3 | 0.20 REF | | |
| Overall Length | D | 2.00 BSC | | |
| Overall Width | E | 3.00 BSC | | |
| Exposed Pad Length | D2 | 1.20 | - | 1.60 |
| Exposed Pad Width | E2 | 1.20 | - | 1.60 |
| Contact Width | b | 0.20 | 0.25 | 0.30 |
| Contact Length | L | 0.25 | 0.30 | 0.45 |
| Contact-to-Exposed Pad | К | 0.20 | - | - |

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars at ends.
- 3. Package is saw singulated
- 4. Dimensioning and tolerancing per ASME Y14.5M

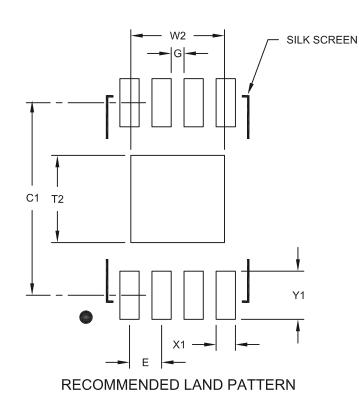
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-129C Sheet 2 of 2

8-Lead Plastic Dual Flat, No Lead Package (MN) – 2x3x0.75 mm Body [TDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



| | Ν | MILLIMETER | S | |
|----------------------------|------------------|-------------------|----------|------|
| Dimensior | Dimension Limits | | NOM | MAX |
| Contact Pitch | E | | 0.50 BSC | |
| Optional Center Pad Width | W2 | | | 1.46 |
| Optional Center Pad Length | T2 | | | 1.36 |
| Contact Pad Spacing | C1 | | 3.00 | |
| Contact Pad Width (X8) | X1 | | | 0.30 |
| Contact Pad Length (X8) | Y1 | | | 0.75 |
| Distance Between Pads | G | 0.20 | | |

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2129A

APPENDIX A: REVISION HISTORY

Revision A (4/2009)

Original release of this document.

Revision B (12/2012)

Revised Table 1-2, Param. 21.

^{© 2009-2012} Microchip Technology Inc.

25XX080C/D

NOTES:

THE MICROCHIP WEB SITE

Microchip provides online support via our WWW site at www.microchip.com. This web site is used as a means to make files and information easily available to customers. Accessible by using your favorite Internet browser, the web site contains the following information:

- Product Support Data sheets and errata, application notes and sample programs, design resources, user's guides and hardware support documents, latest software releases and archived software
- General Technical Support Frequently Asked Questions (FAQ), technical support requests, online discussion groups, Microchip consultant program member listing
- Business of Microchip Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

CUSTOMER CHANGE NOTIFICATION SERVICE

Microchip's customer notification service helps keep customers current on Microchip products. Subscribers will receive e-mail notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, access the Microchip web site at www.microchip.com, click on Customer Change Notification and follow the registration instructions.

CUSTOMER SUPPORT

Users of Microchip products can receive assistance through several channels:

- Distributor or Representative
- Local Sales Office
- Field Application Engineer (FAE)
- Technical Support
- Development Systems Information Line

Customers should contact their distributor, representative or field application engineer (FAE) for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in the back of this document.

Technical support is available through the web site at: http://support.microchip.com

^{© 2009-2012} Microchip Technology Inc.

READER RESPONSE

It is our intention to provide you with the best documentation possible to ensure successful use of your Microchip product. If you wish to provide your comments on organization, clarity, subject matter, and ways in which our documentation can better serve you, please FAX your comments to the Technical Publications Manager at (480) 792-4150.

Please list the following information, and use this outline to provide us with your comments about this document.

| To: | Technical Publications Manager | Total Pages Sent | | | | | | |
|---------------------------|--|---|--|--|--|--|--|--|
| RE: | Reader Response | | | | | | | |
| From | : Name | | | | | | | |
| | | | | | | | | |
| | Address | | | | | | | |
| | City / State / ZIP / Country | | | | | | | |
| | Telephone: () | FAX: () | | | | | | |
| Application (optional): | | | | | | | | |
| Would you like a reply?YN | | | | | | | | |
| Devi | Device: 25XX080C/D Literature Number: DS22151B | | | | | | | |
| Ques | stions: | | | | | | | |
| 1. V | What are the best features of this do | ocument? | | | | | | |
| | | | | | | | | |
| | | | | | | | | |
| 2. ⊦ | How does this document meet your | hardware and software development needs? | | | | | | |
| _ | | | | | | | | |
| _ | | | | | | | | |
| 3. E | Do you find the organization of this of | document easy to follow? If not, why? | | | | | | |
| _ | | | | | | | | |
| _ | | | | | | | | |
| 4. V | What additions to the document do | you think would enhance the structure and subject? | | | | | | |
| _ | | | | | | | | |
| | | | | | | | | |
| 5. V | What deletions from the document of | could be made without affecting the overall usefulness? | | | | | | |
| _ | | | | | | | | |
| - - | | | | | | | | |
| 6. I: | s there any incorrect or misleading | mornation (what and where)? | | | | | | |
| _ | | | | | | | | |
| - 7. F | How would you improve this docume | ent? | | | | | | |
| <i>.</i> . 1 | | | | | | | | |
| _ | | | | | | | | |
| | | | | | | | | |

DS22151B-page 30

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

| PART NO. | × | - <u>x /xx</u> | | Examples: |
|-----------------------|---|---|---|--|
| Device | Tape & Reel 25AA080C 25AA080D 25LC080C 25LC080D | 8 Kbit, 1.8V, 32 Byte Page SPI Serial EEPROM 8 Kbit, 2.5V, 16 Byte Page SPI Serial EEPROM | | 25AA080C-I/MS = 8 Kbit, 16-byte page, 1.8V Serial EEPROM, Industrial temp., MSOP package 25AA080CT-I/SN = 8 Kbit, 16-byte page, 1.8V Serial EEPROM, Industrial temp., Tape & Reel, SOIC package 25LC080DT-I/SN = 8 Kbit, 32-byte page, 2.5V Serial EEPROM, Industrial temp., Tape & Reel, SOIC package |
| Tape & Reel: | Blank = T = | Standard packaging Tape & Reel | | d) 25LC080DT-I/ST = 8 Kbit, 32-byte page, 2.5V Serial EEPROM, Industrial temp., Tape & Reel, TSSOP package |
| Temperature Range: | = E = | -40°C to+85°C -40°C to+125°C | | |
| Package: Note 1: | MS = P = SN = ST = MNY ⁽¹⁾ = | Plastic MSOP (Micro Small Outline), 8-lead Plastic DIP (300 mil body), 8-lead Plastic SOIC (3.90 mm body), 8-lead TSSOP, 8-lead 8-lead 2x3 mm TDFN kel Palladium Gold (NiPdAu) finish. | | |
| <u> </u> | | | 1 | |

^{© 2009-2012} Microchip Technology Inc.

25XX080C/D

NOTES:

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PIC³² logo, rfPIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

FilterLab, Hampshire, HI-TECH C, Linear Active Thermistor, MTP, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

Analog-for-the-Digital Age, Application Maestro, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, HI-TIDE, In-Circuit Serial Programming, ICSP, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, mTouch, Omniscient Code Generation, PICC, PICC-18, PICDEM, PICDEM.net, PICkit, PICtail, REAL ICE, rfLAB, Select Mode, SQI, Serial Quad I/O, Total Endurance, TSHARC, UniWinDriver, WiperLock, ZENA and Z-Scale are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

GestIC and ULPP are registered trademarks of Microchip Technology Germany II GmbH & Co. & KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2009-2012, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

ISBN: 9781620767221

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and mulfacture of development systems is ISO 9001:2000 certified.

© 2009-2012 Microchip Technology Inc.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: http://www.microchip.com/ support

Web Address: www.microchip.com

Atlanta Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL Tel: 630-285-0071 Fax: 630-285-0075

Cleveland Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Indianapolis Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto Mississauga, Ontario, Canada Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431 Australia - Sydney

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Hangzhou Tel: 86-571-2819-3187

Fax: 86-571-2819-3189 China - Hong Kong SAR

Tel: 852-2943-5100 Fax: 852-2401-3431

China - Nanjing Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen Tel: 86-755-8864-2200 Fax: 86-755-8203-1760

China - Wuhan Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Xiamen Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai Tel: 86-756-3210040 Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

Japan - Osaka Tel: 81-6-6152-7160 Fax: 81-6-6152-9310

Japan - Tokyo Tel: 81-3-6880- 3770 Fax: 81-3-6880-3771

Korea - Daegu Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung Tel: 886-7-213-7828 Fax: 886-7-330-9305

Taiwan - Taipei Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels Tel: 43-7242-2244-39 Fax: 43-7242-2244-393 Denmark - Copenhagen Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Munich Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen Tel: 31-416-690399 Fax: 31-416-690340

Spain - Madrid Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

UK - Wokingham Tel: 44-118-921-5869 Fax: 44-118-921-5820